The listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (Original) A method of manufacturing a light emitting device having a light emitting element composed of an anode, a cathode, and an organic compound layer, comprising the steps of:

applying a reverse bias to the light emitting element;

determining fault portions of the light emitting element; and

irradiating a laser to the fault portions.

2. (Original) A method of manufacturing a light emitting device having a light emitting element composed of an anode, a cathode, and an organic compound layer, comprising the steps of:

applying a reverse bias to the light emitting element;

determining fault portions of the light emitting element by detecting light emitting positions; and

irradiating a laser to the fault portions.

3. (Original) A method of manufacturing a light emitting device having a light emitting element composed of an anode, a cathode, and an organic compound layer, comprising the steps of:

applying a reverse bias to the light emitting element;

determining fault portions of the light emitting element; and

irradiating a laser to the fault portions, making the fault portions insulating.

4. (Original) A method of manufacturing a light emitting device having a light

emitting element composed of an anode, a cathode, and an organic compound layer, comprising the steps of:

applying a reverse bias to the light emitting element;

determining fault portions of the light emitting element by detecting light emitting positions; and

irradiating a laser to the fault portions, making the fault portions insulating.

5. (Original) A method of manufacturing a light emitting device having a light emitting element composed of an anode, a cathode, and an organic compound layer, comprising the steps of:

applying a reverse bias to the light emitting element;

determining fault portions of the light emitting element; and

irradiating a laser to the fault portions, making inverse direction electric current flow smaller than before the laser irradiation.

6. (Original) A method of manufacturing a light emitting device having a light emitting element composed of an anode, a cathode, and an organic compound layer, comprising the steps of:

applying a reverse bias to the light emitting element;

determining fault portions of the light emitting element by detecting light emitting positions; and

irradiating a laser to the fault portions, making inverse direction electric current flow smaller than before the laser irradiation.

7. (Original) A method of manufacturing a light emitting device according to claim 1, wherein the organic compound layer contacts the cathode, and the anode contacts the organic compound layer.

8. (Original) A method of manufacturing a light emitting device according to claim 2, wherein the organic compound layer contacts the cathode, and the anode contacts the organic compound layer.

9. (Original) A method of manufacturing a light emitting device according to claim 3, wherein the organic compound layer contacts the cathode, and the anode contacts the organic compound layer.

10. (Original) A method of manufacturing a light emitting device according to claim 4, wherein the organic compound layer contacts the cathode, and the anode contacts the organic compound layer.

11. (Original) A method of manufacturing a light emitting device according to claim 5, wherein the organic compound layer contacts the cathode, and the anode contacts the organic compound layer.

12. (Original) A method of manufacturing a light emitting device according to claim 6, wherein the organic compound layer contacts the cathode, and the anode contacts the organic compound layer.

13. (Original) A method of manufacturing a light emitting device according to claim 1, wherein the organic compound layer comprises light emitting layers, hole injecting layers, hole transporting layers, electron transporting layers, and electron injecting layers.

14. (Original) A method of manufacturing a light emitting device according to claim 2, wherein the organic compound layer comprises light emitting layers, hole injecting layers, hole transporting layers, electron transporting layers, and electron

injecting layers.

15. (Original) A method of manufacturing a light emitting device according to claim 3, wherein the organic compound layer comprises light emitting layers, hole injecting layers, hole transporting layers, electron transporting layers, and electron injecting layers.

16. (Original) A method of manufacturing a light emitting device according to claim 4, wherein the organic compound layer comprises light emitting layers, hole injecting layers, hole transporting layers, electron transporting layers, and electron injecting layers.

17. (Original) A method of manufacturing a light emitting device according to claim 5, wherein the organic compound layer comprises light emitting layers, hole injecting layers, hole transporting layers, electron transporting layers, and electron injecting layers.

18. (Original) A method of manufacturing a light emitting device according to claim 6, wherein the organic compound layer comprises light emitting layers, hole injecting layers, hole transporting layers, electron transporting layers, and electron injecting layers.

19. (Original) A method of manufacturing a light emitting device according to claim 1, further having at least a thin film transistor.

20. (Original) A method of manufacturing a light emitting device according to claim 2, further having at least a thin film transistor.

21. (Original) A method of manufacturing a light emitting device according to claim 3, further having at least a thin film transistor.

22. (Original) A method of manufacturing a light emitting device according to claim 4, further having at least a thin film transistor.

23. (Original) A method of manufacturing a light emitting device according to claim 5, further having at least a thin film transistor.

24. (Original) A method of manufacturing a light emitting device according to claim 6, further having at least a thin film transistor.

25. (Original) A method of manufacturing a light emitting device according to claim 1, wherein the reverse bias is applied in a range of 1 to 15 V.

26. (Original) A method of manufacturing a light emitting device according to claim 2, wherein the reverse bias is applied in a range of 1 to 15 V.

27. (Original) A method of manufacturing a light emitting device according to claim 3, wherein the reverse bias is applied in a range of 1 to 15 V.

28. (Original) A method of manufacturing a light emitting device according to claim 4, wherein the reverse bias is applied in a range of 1 to 15 V.

29. (Original) A method of manufacturing a light emitting device according to claim 5, wherein the reverse bias is applied in a range of 1 to 15 V.

30. (Original) A method of manufacturing a light emitting device according to

claim 6, wherein the reverse bias is applied in a range of 1 to 15 V.

31.-34. (Canceled)

35. (Original) A method of manufacturing a light emitting device according to claim 1, wherein the light emitting device is at least one device selected from the group consisting of: a digital still camera, a laptop computer, a mobile computer, a DVD player, a goggle type display, a video camera and a cellular phone.

36. (Original) A method of manufacturing a light emitting device according to claim 2, wherein the light emitting device is at least one device selected from the group consisting of: a digital still camera, a laptop computer, a mobile computer, a DVD player, a goggle type display, a video camera and a cellular phone.

37. (Original) A method of manufacturing a light emitting device according to claim 3, wherein the light emitting device is at least one device selected from the group consisting of: a digital still camera, a laptop computer, a mobile computer, a DVD player, a goggle type display, a video camera and a cellular phone.

38. (Original) A method of manufacturing a light emitting device according to claim 4, wherein the light emitting device is at least one device selected from the group consisting of: a digital still camera, a laptop computer, a mobile computer, a DVD player, a goggle type display, a video camera and a cellular phone.

39. (Original) A method of manufacturing a light emitting device according to claim 5, wherein the light emitting device is at least one device selected from the group consisting of: a digital still camera, a laptop computer, a mobile computer, a DVD player, a goggle type display, a video camera and a cellular phone.

40. (Original) A method of manufacturing a light emitting device according to claim 6, wherein the light emitting device is at least one device selected from the group consisting of: a digital still camera, a laptop computer, a mobile computer, a DVD player, a goggle type display, a video camera and a cellular phone.